Docket No. AM1562D

CLEAN COPY OF THE CLAIMS AS AMENDED

- 1 (Amended). An etch mixture for silicon consisting essentially of a fluorine-containing gas selected from the group consisting of SF_6 , Si_2F_6 and SiF_4 together with HBr and oxygen.
- 2. An etch mixture according to claim 1 wherein the mixturte additionally includes a noble gas.
- 3. An etch mixture according to claim 1 wherein the mixture contains SF_6 .
- 4. An etch mixture according to claim 3 wherein the mixture additionally includes Si_2F_6 and Si_4 .
- 5. An etch mixture according to claim 3 wherein the volume ratio of $HBr: SF_6$ is 0.1 to 10.
- 6. An etch mixture according to claim 3 wherein the volume ratio of HBr and $SF_6\colon O_2$ is 0.1 to 10.